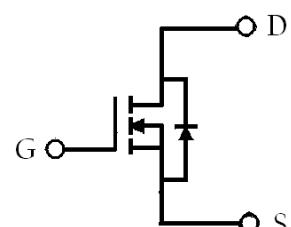
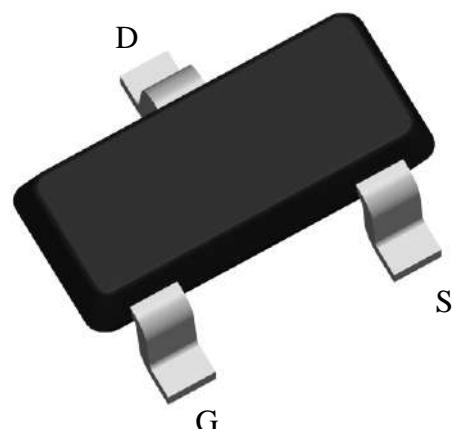


500V N-Channel Enhancement Mode MOSFET

Features:

- $V_{DS}=500V$
- $R_{DS(ON)(typ)}=11.8\Omega$ @ $V_{GS}=10V$, $I_D=0.4A$
- Low gate charge
- Excellent thermal and electrical capabilities
- Pb-free lead plating and halogen-free package

SOT-23



BV_{DSS}	500V
I_D @ $V_{GS}=10V$, $T_A=25^\circ C$	0.35A
$R_{DS(ON)(TYP)}$ @ $V_{GS}=10V$, $I_D=0.4A$	11.8Ω

G : Gate S : Source D : Drain

Ordering Information

Device	Package	Shipping
KWN1N50C	SOT-23 (Pb-free lead plating and halogen-free package)	3000 pcs / tape & reel

Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Drain-Source Voltage	V _{DS}	500	V
Gate-Source Voltage	V _{GS}	±30	
Continuous Drain Current @ TA=25°C (Note 3)	I _D	0.35	A
Continuous Drain Current @ TA=70°C (Note 3)		0.28	
Pulsed Drain Current (Note 1, 2)	I _{DM}	1.4	A
Body Diode Continuous Forward Current	I _S	0.35	
Maximum Power Dissipation @ TA=25°C	P _D	1.38	W
Linear Derating Factor		0.01	W/°C
Thermal Resistance, Junction-to-Ambient (Note 3)	R _{th,ja}	90	°C/W
Operating Junction and Storage Temperature	T _j , T _{stg}	-55~+150	°C

Note : 1. Pulse width limited by maximum junction temperature.

2. Pulse width≤ 300μs, duty cycle≤2%.

3. Surface mounted on 1 in² copper pad of FR-4 board; 270°C/W when mounted on minimum copper pad.

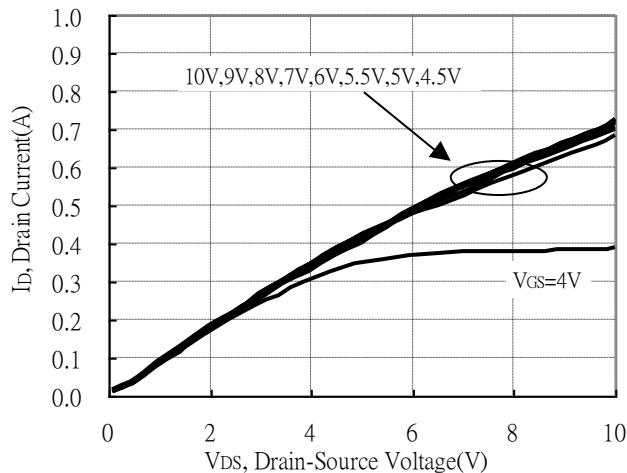
Electrical Characteristics (T_j=25°C, unless otherwise specified)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions	
Static						
BV _{DSS}	500	-	-	V	V _{GS} =0V, I _D =250μA	
V _{GS(th)}	2	-	4		V _{DS} =V _{GS} , I _D =250μA	
G _{FS}	-	0.7	-	S	V _{DS} =10V, I _D =0.3A	
I _{GSS}	-	-	±100	nA	V _{GS} =±30V, V _{DS} =0V	
I _{DSS}	-	-	1	μA	V _{DS} =500V, V _{GS} =0V	
	-	-	10		V _{DS} =500V, V _{GS} =0V, T _j =55°C	
*R _{D(S(ON))}	-	11.8	16	Ω	V _{GS} =10V, I _D =0.4A	
Dynamic						
C _{iss}	-	63.7	-	pF	V _{DS} =250V, V _{GS} =0V, f=1MHz	
C _{oss}	-	8.5	-			
C _{rss}	-	9.2	-			
*t _{d(ON)}	-	4.2	-	ns	V _{DS} =250V, I _D =0.4A, V _{GS} =10V, R _G =6Ω	
*t _r	-	7.2	-			
*t _{d(OFF)}	-	9.8	-			
*t _f	-	23	-			
*Q _g	-	3.7	-	nC	V _{DS} =400V, I _D =0.4A, V _{GS} =10V	
*Q _{gs}	-	1	-			
*Q _{gd}	-	0.9	-			
R _g	-	6.4	-	Ω	f=1MHz	
Source-Drain Diode						
*V _{SD}	-	0.82	1.2	V	V _{GS} =0V, I _S =0.4A	
*trr	-	212.9	-	ns	I _F =0.5A, dI _F /dt=100A/μs	
*Qrr	-	136.2	-	nC		

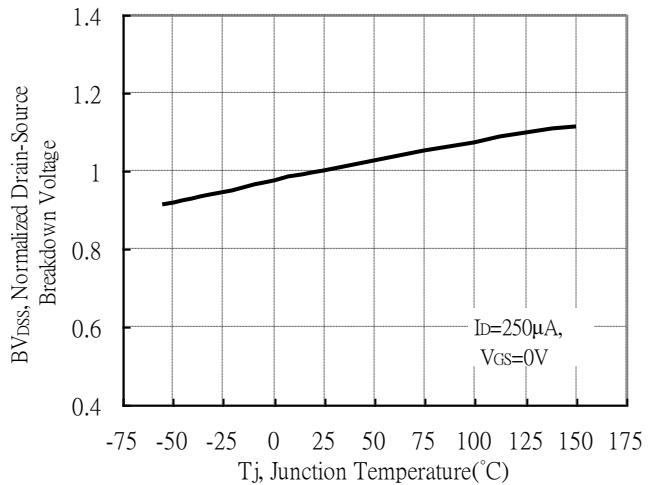
*Pulse Test : Pulse Width ≤300μs, Duty Cycle≤2%

Typical Characteristics

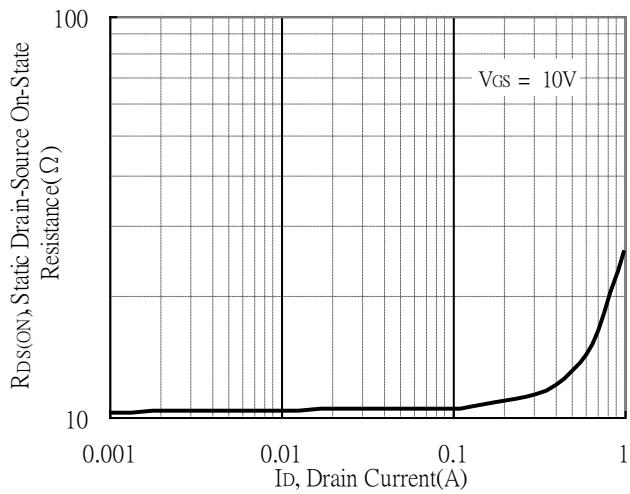
Typical Output Characteristics



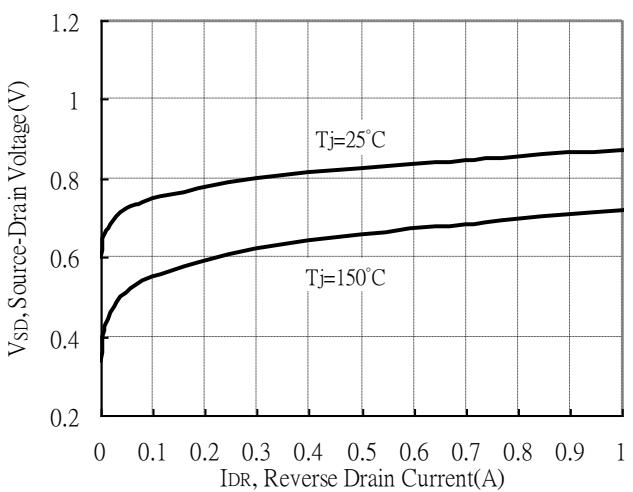
Breakdown Voltage vs Ambient Temperature



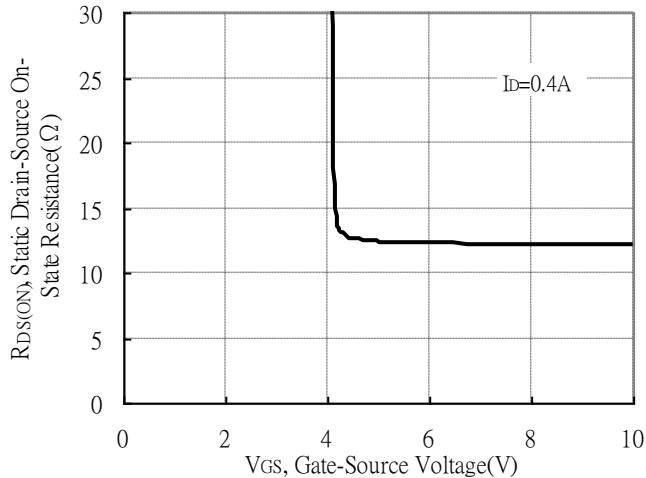
Static Drain-Source On-State resistance vs Drain Current



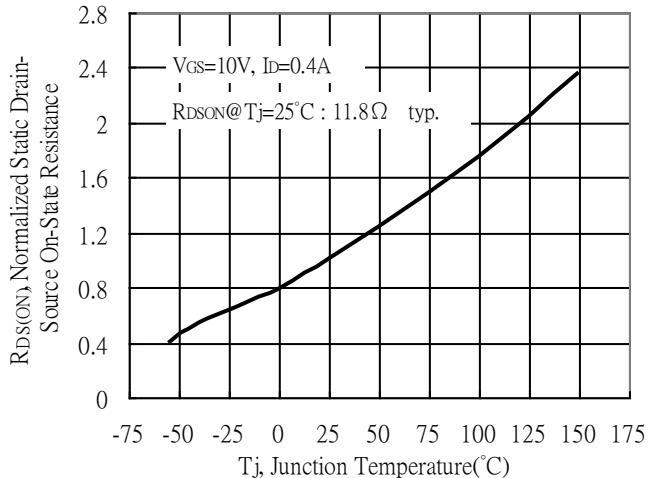
Reverse Drain Current vs Source-Drain Voltage



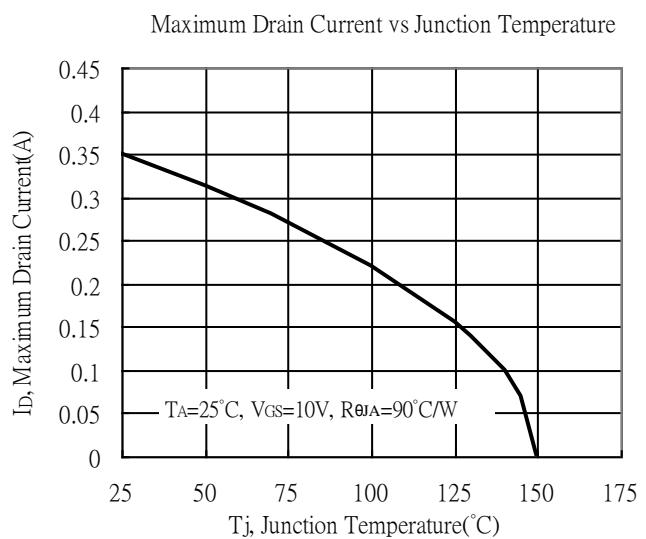
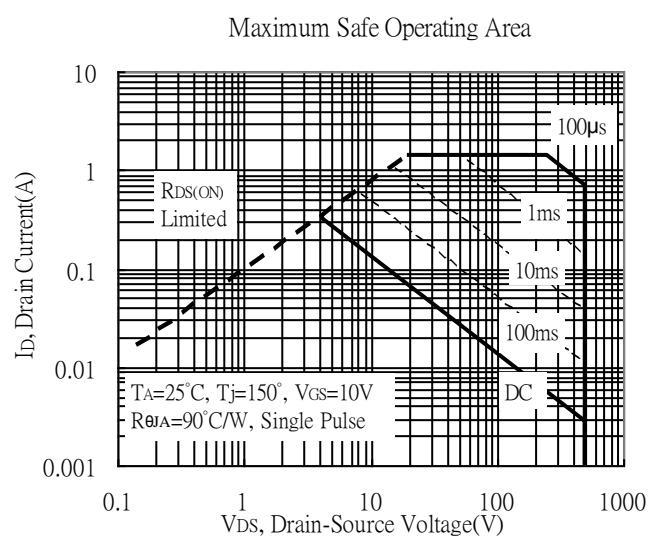
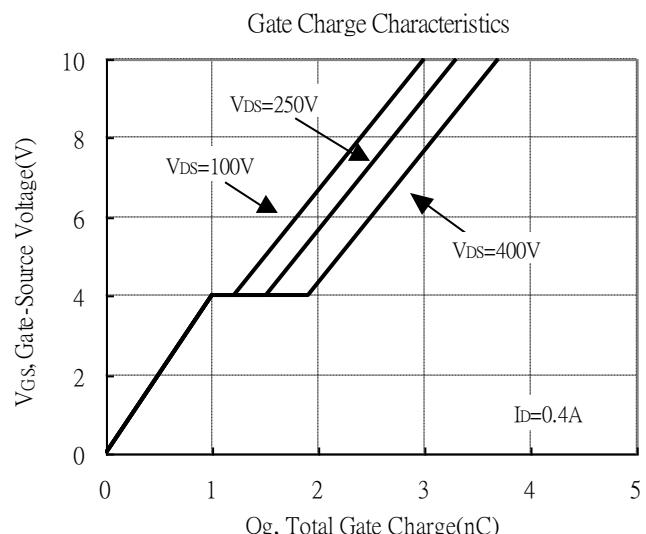
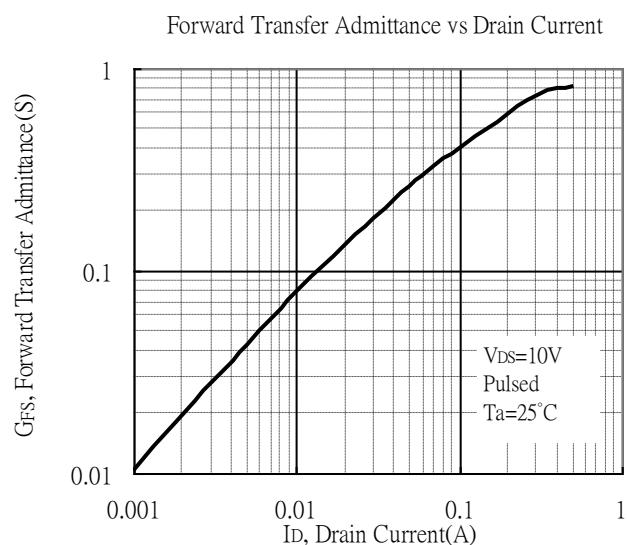
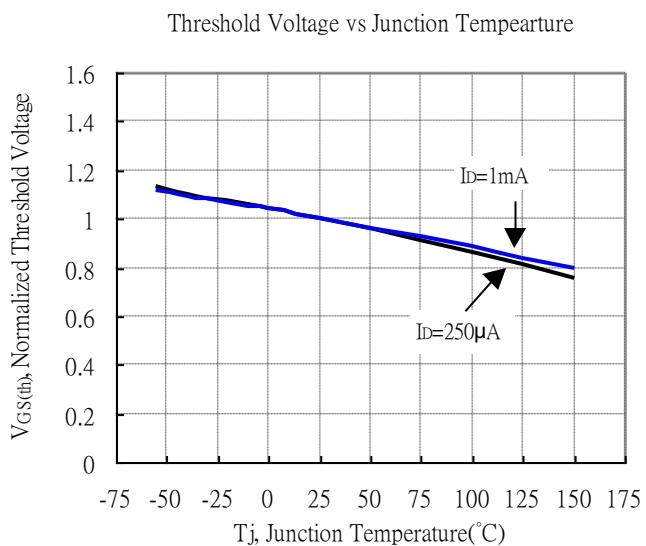
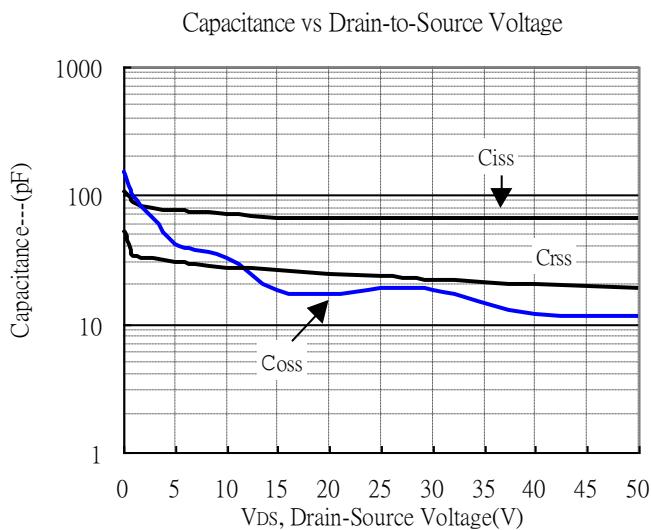
Static Drain-Source On-State Resistance vs Gate-Source Voltage



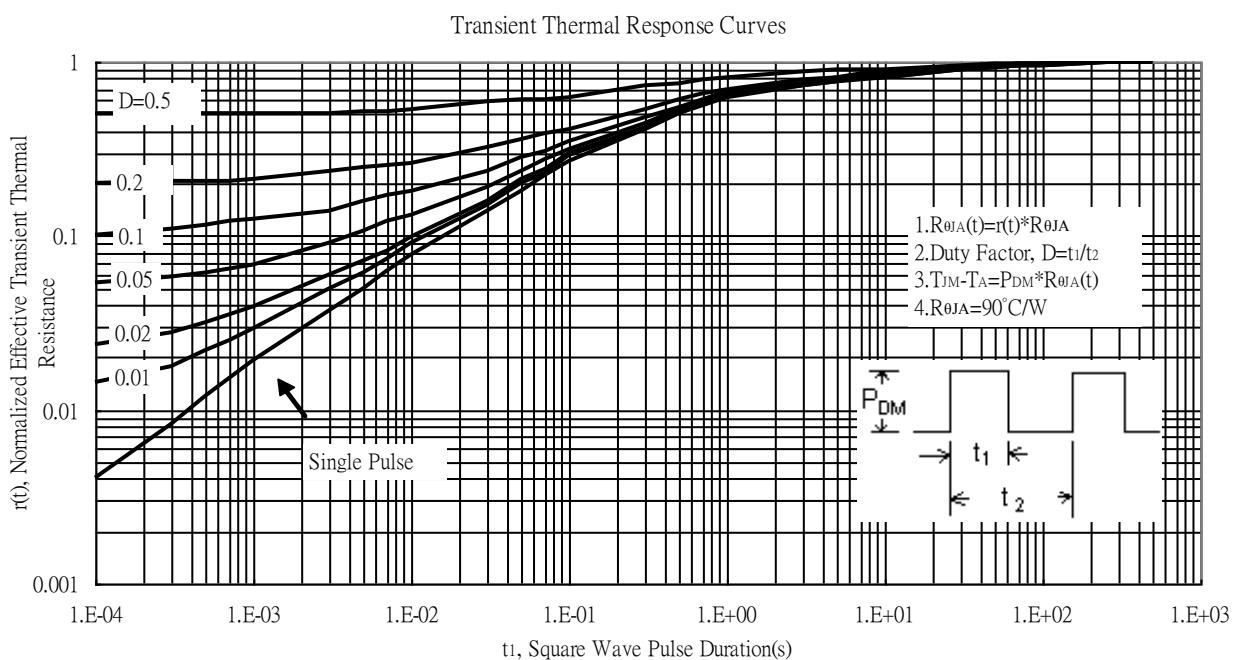
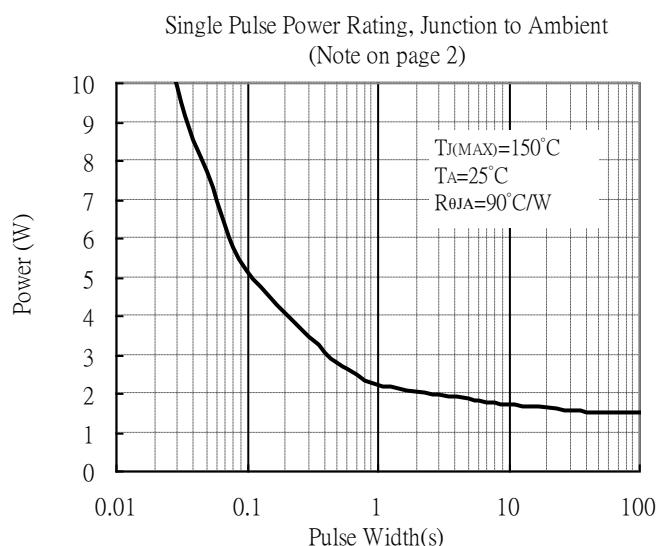
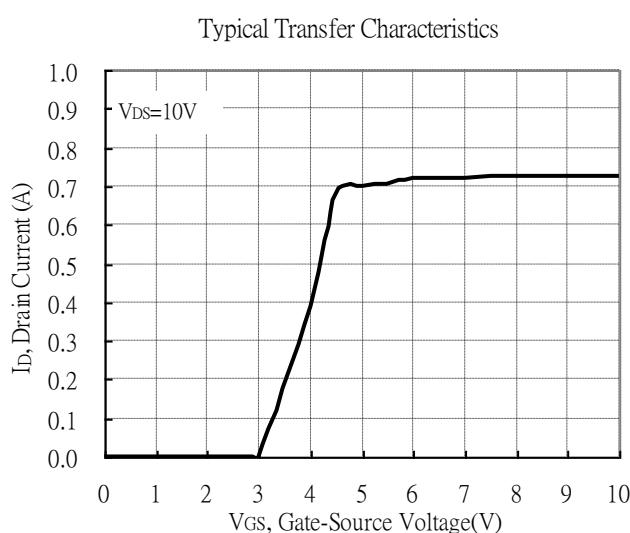
Drain-Source On-State Resistance vs Junction Temperature



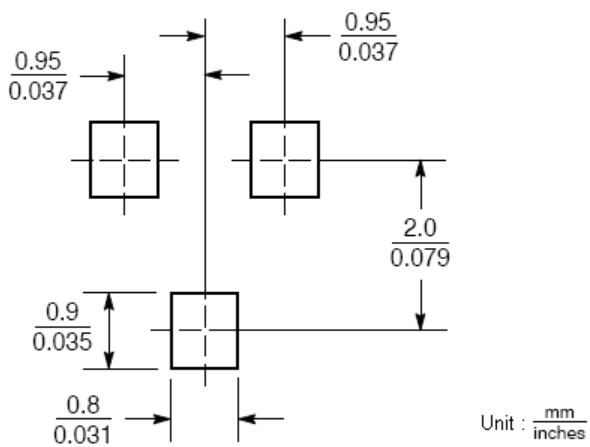
Typical Characteristics(Cont.)



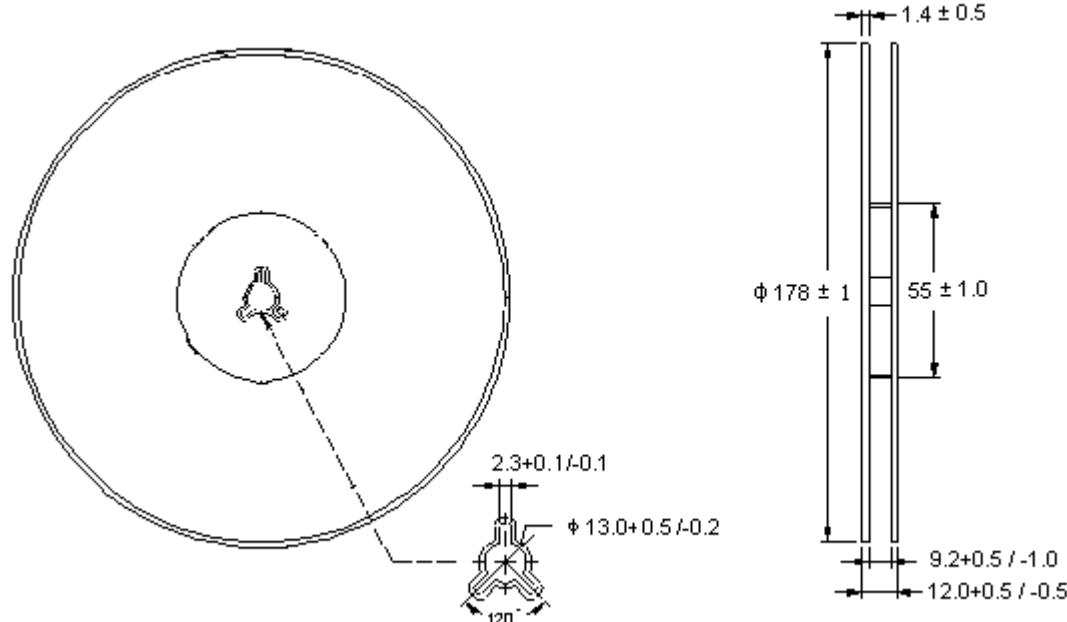
Typical Characteristics(Cont.)



Recommended Soldering Footprint

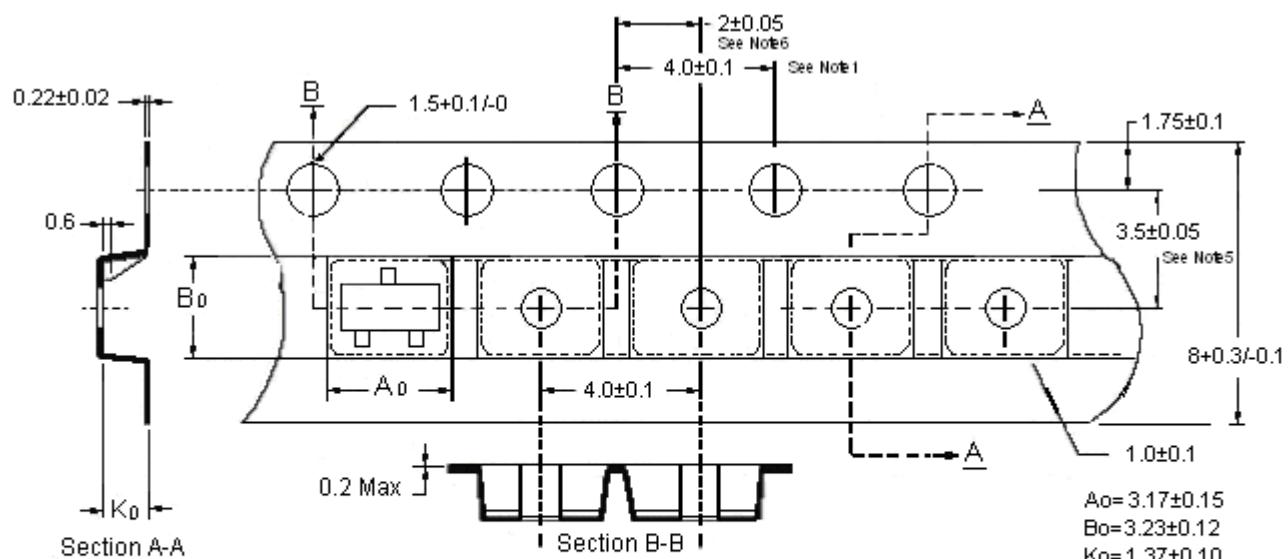


Reel Dimension



Unit: millimeter

Carrier Tape Dimension

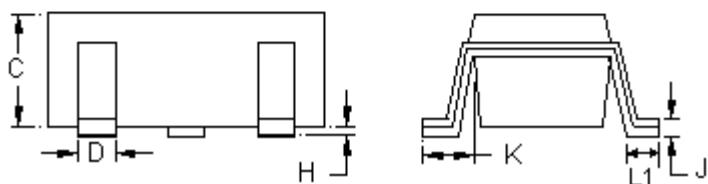
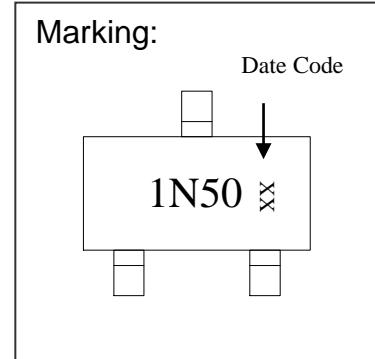
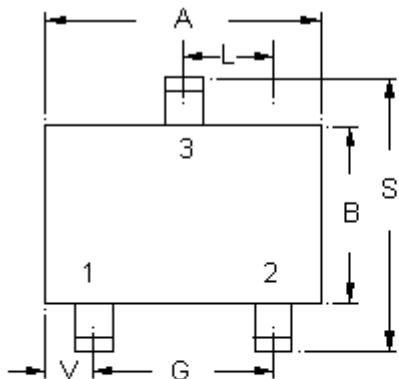


Notes:

1. 10 sprocket hole pitch cumulative tolerance ± 0.2 .
2. Camber not to exceed 1mm in 100mm.
3. Material : conductive Black Polystyrene.
4. A_0 & B_0 measured on a plane 0.3mm above the bottom of the pocket.
5. K_0 measured from a plane on the inside bottom of the pocket to the top surface of the carrier.
6. Pocket position relative to sprocket hole measured as true position of pocket, not pocket hole.

Unit : millimeter

SOT-23 Dimension



3-Lead SOT-23 Plastic Surface Mounted Package

Style: Pin 1.Gate 2.Source 3.Drain

*: Typical

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.1102	0.1204	2.80	3.04	J	0.0032	0.0079	0.08	0.20
B	0.0472	0.0669	1.20	1.70	K	0.0118	0.0266	0.30	0.67
C	0.0335	0.0512	0.89	1.30	L	0.0335	0.0453	0.85	1.15
D	0.0118	0.0197	0.30	0.50	S	0.0830	0.1161	2.10	2.95
G	0.0669	0.0910	1.70	2.30	V	0.0098	0.0256	0.25	0.65
H	0.0000	0.0040	0.00	0.10	L1	0.0118	0.0197	0.30	0.50